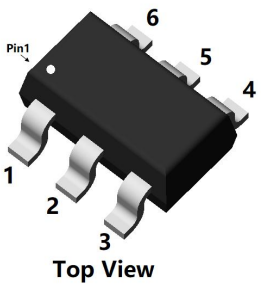
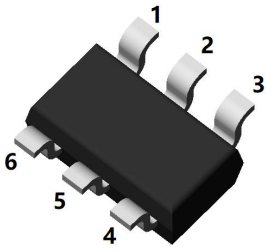
N-Channel Enhancement Mode Field Effect Transistor

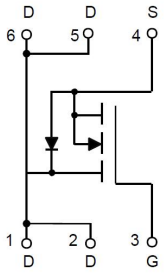


Top View



Bottom View

SOT-23-6L



Product Summary

- V_{DS} 100V
- I_D 3.0A
- $R_{DS(ON)}$(at V_{GS}= 10V) ＜120mohm
- $R_{DS(ON)}$(at V_{GS}= 4.5V) ＜140mohm

General Description

- Trench Power MV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- DC-DC Converters
- Power management functions

■ Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	100	V
Gate-source Voltage		V_{GS}	±20	V
Drain Current	T_A=25℃	I_D	3	A
	T_A=70℃		2.4	
Pulsed Drain Current [A]		I_{DM}	12	A
Single Pulse Avalanche Energy		E_{AS}	8	mJ
Total Power Dissipation @ T_A=25℃		P_D	1.5	W
Thermal Resistance Junction-to-Ambient [B]		$R_{\theta JA}$	83	℃/ W
Thermal Resistance From Junction To Lead		R_{thJL}	36	℃/W
Junction and Storage Temperature Range		T_J ,T_{STG}	-55～+150	℃

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
S03N10A	F2	1003	3000	30000	120000	7"

■ Electrical Characteristics (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}= 0V, I_D=250μA	100			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V,V_{GS}=0V			1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}= ±20V, V_{DS}=0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}= V_{GS}, I_D=250μA	1.1	1.8	3.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}= 10V, I_D=3A		95	120	mΩ
		V_{GS}= 4.5V, I_D=2.4A		100	140	
Diode Forward Voltage	V_{SD}	I_S=3A,V_{GS}=0V		0.8	1.2	V
Maximum Body-Diode Continuous Current	I_S				3	A
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{DS}=50V,V_{GS}=0V,f=1MHZ		1070		pF
Output Capacitance	C_{oss}			33		
Reverse Transfer Capacitance	C_{rss}			30		
Switching Parameters						
Total Gate Charge	Q_g	V_{GS}=10V,V_{DS}=50V,I_D=10A		26		nC
Gate-Source Charge	Q_{gs}			5.4		
Gate-Drain Charge	Q_{gd}			5.8		
Reverse Recovery Charge	Q_{rr}	I_F=10A, di/dt=100A/us		30.1		
Reverse Recovery Time	t_{rr}			40		ns
Turn-on Delay Time	$t_{D(on)}$	V_{GS}=10V,V_{DD}=50V,R_L=6.4Ω R_{GEN}=3Ω		7		
Turn-on Rise Time	t_r			24		
Turn-off Delay Time	$t_{D(off)}$			24		
Turn-off fall Time	t_f			31		

A. Pulse Test: Pulse Width≤300us,Duty cycle ≤2%.

B. $R_{\theta JA}$ is the sum of the junction-to-lead and lead-to-ambient thermal resistance, where the lead thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JL}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

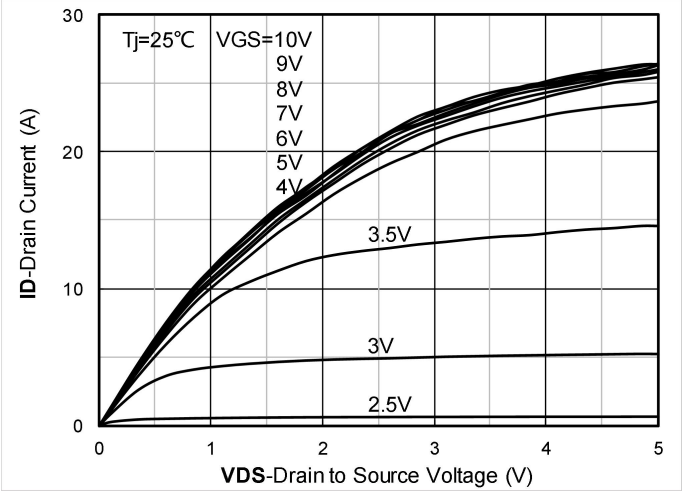


Figure 1. Output Characteristics

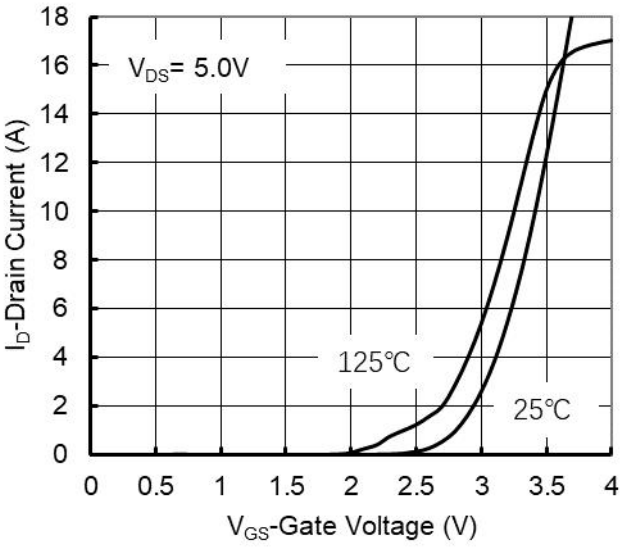


Figure 2. Transfer Characteristics

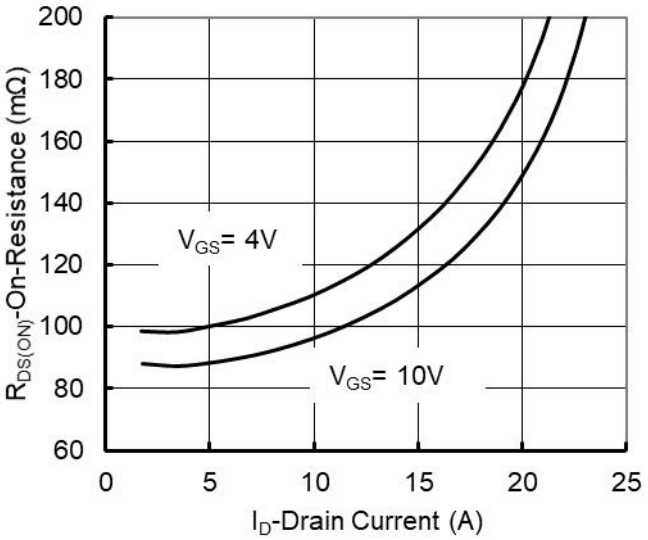


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

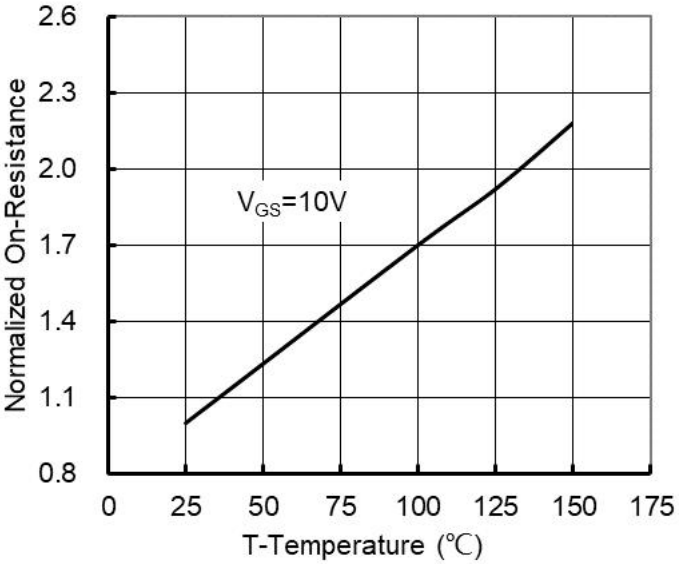


Figure 4. On-Resistance vs. Junction Temperature

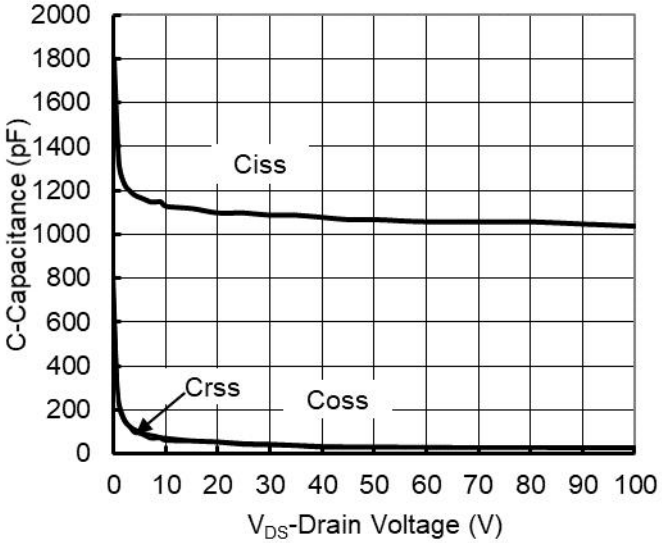


Figure 5. Capacitance Characteristics

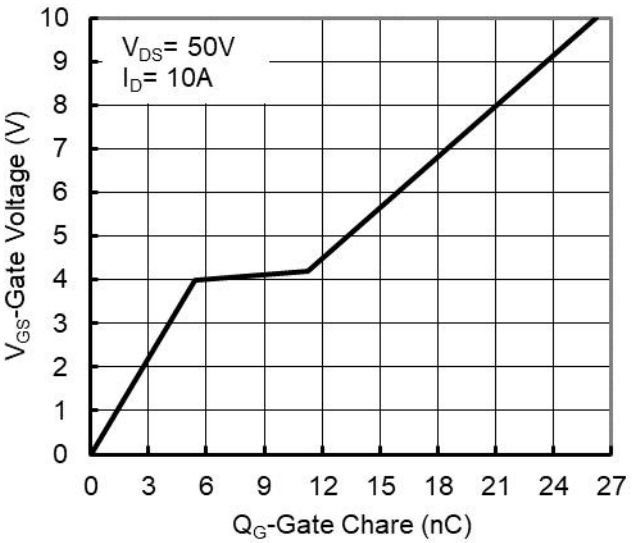


Figure 6. Gate Charge

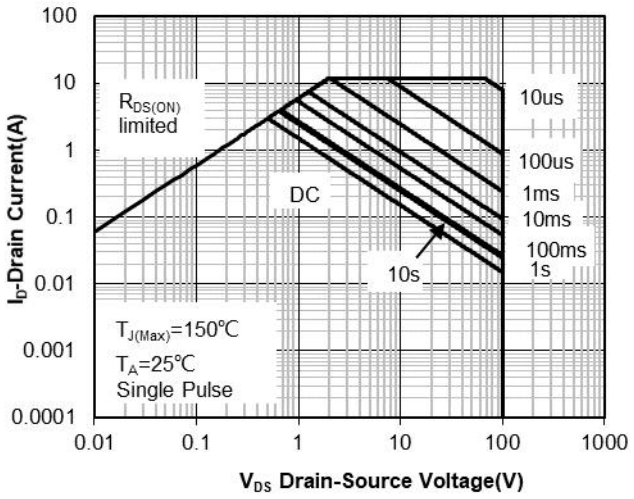


Figure 7. Safe Operation Area

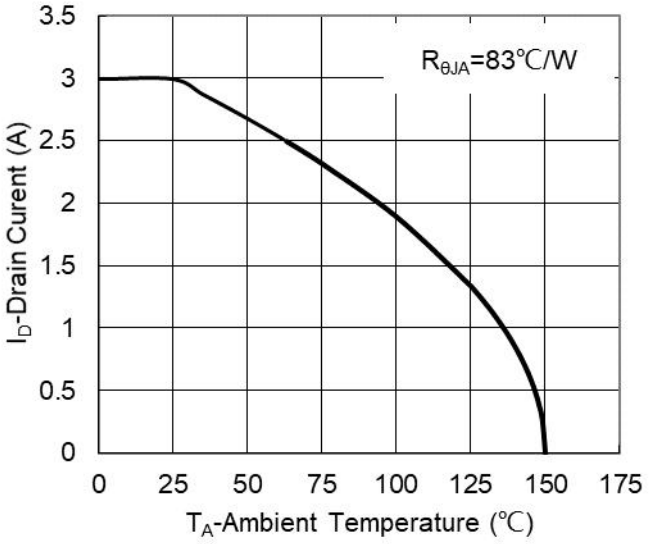


Figure 8. Maximum Continuous Drain Current vs Ambient Temperature

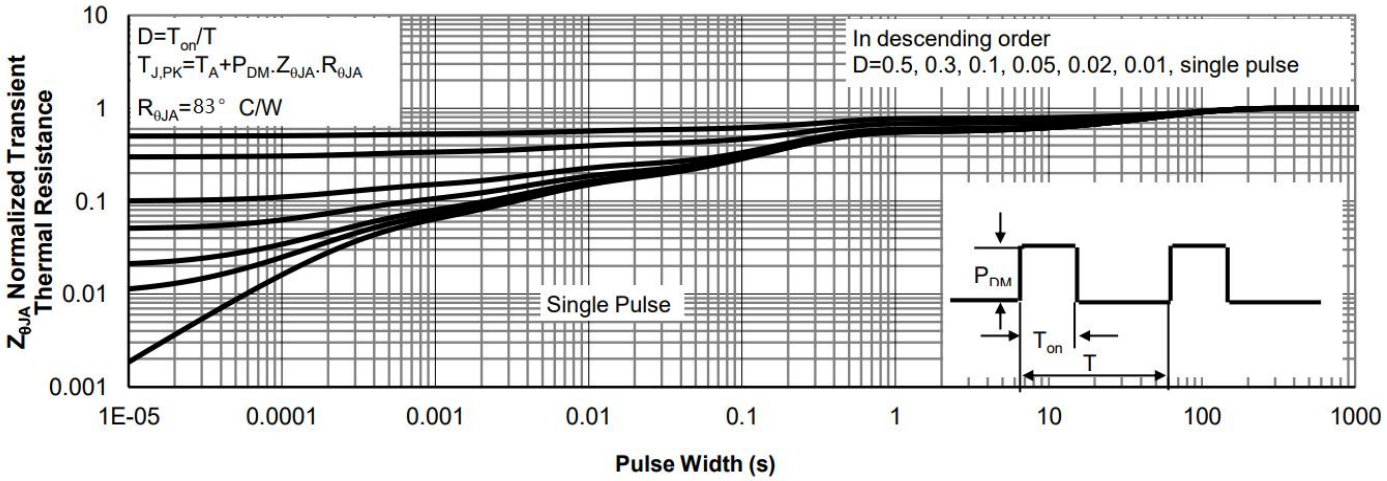


Figure 9. Normalized Maximum Transient Thermal Impedance

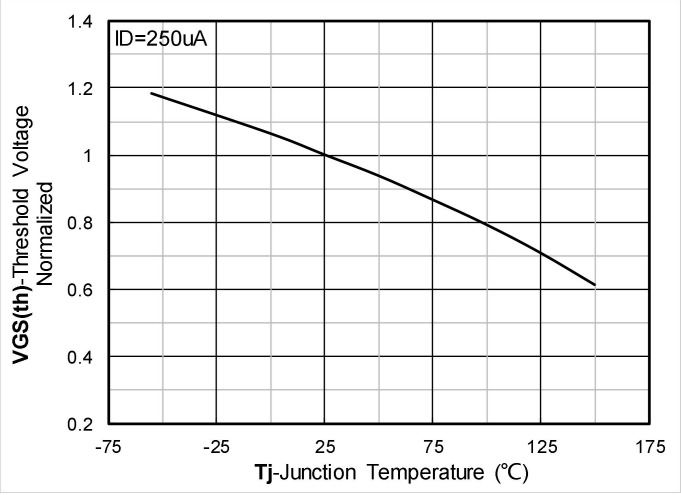
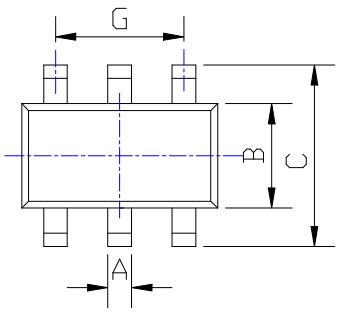
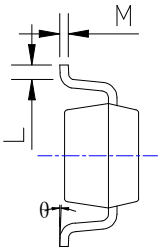


Figure 10. Normalized Threshold voltage

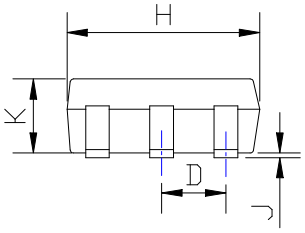
■SOT-23-6L Package information



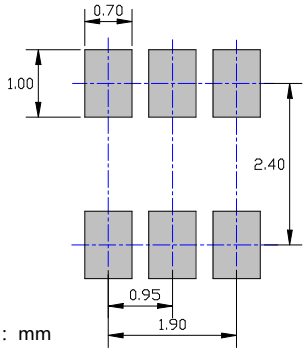
TOP VIEW



SIDE VIEW



SIDE VIEW



Unit: mm

Suggested Solder Pad Layout

DIMENSIONS				
SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.012	0.020	0.300	0.500
B	0.059	0.067	1.500	1.700
C	0.104	0.116	2.650	2.950
D	0.037BSC		0.950BSC	
G	0.075BSC		1.900BSC	
H	0.111	0.119	2.820	3.020
J	0.000	0.004	0.000	0.100
K	0.041	0.045	1.050	1.150
L	0.012	0.024	0.300	0.600
M	0.004	0.008	0.100	0.200
θ	0°	8°	0°	8°

Note:
1.Controlling dimension:in millimeters.
2.General tolerance:+/-0.05mm.
3.The pad layout is for reference purposes only.

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